L Number	Hits	Search Text	DB	Time stamp
44	3	(US-4993396-\$).did. or (WO-9844687-\$ or WO-9966557-\$).did.	USPAT; EPO	2004/11/08 08:05
45	3	(US-4993396-\$).did. or (WO-9844687-\$ or WO-9966557-\$).did.	DERWENT	2004/11/08 09:42
46	3	(((*20020109186*) or (*20040051160*) or (*6624474*)).PN.) and (isolated isolating isolator)	USPAT;	2004/11/08 08:24
	_	(1/0 4000000 t) [1] (1/40 0044007 t) (1/40 000057 t) [1] (1/40 0407400 t)	US-PGPUB	00044440000040
51 52	5	(US-4993396-\$).did. or (WO-9844687-\$ or WO-9966557-\$).did. or (US-6407432-\$).did.	USPAT;	2004/11/08 09:46
			US-PGPUB;	
	2	(110 4002200 @/ 4:4 (M/O 0044007 @ M/O 0000000 @/ 4:4 (110 0407420 @/ 4:4	DERWENT	0004/44/00 00.47
53	3	(US-4993396-\$).did. or (WO-9844687-\$ or WO-9966557-\$).did. or (US-6407432-\$).did.	DERWENT	2004/11/08 09:47
	2	((*11136293*) or (*11317445*)).PN.	USPAT;	2004/11/08 10:08
			US-PGPUB;	
			EPO; JPO;	
54	4	(("20030169808") or ("6603807")).PN.	DERWENT USPAT;	2004/11/08 10:08
	7	((20030 103000) 01 (0003007)).FIV.	US-PGPUB;	2004/11/06 10:06
			1	
			EPO; JPO; DERWENT	
55	2	((("20030169808") or ("6603807")).PN.) and (soi insulator control power)	USPAT;	2004/11/08 10:09
	2	(III 20000 100000) Oi (0000001)).C14.) and (501 insulator Writion power)	US-PGPUB	2004/11/00 10.09
56	2	monolithic adj isolator and @pd>20040422	USPAT;	2004/11/08 10:09
30	_	inononino adjisolator and tepar 20040422	US-PGPUB	2004/11/00 10:09
57	3	(US-6344809-\$ or US-6407432-\$ or US-6603807-\$).did.	USPAT	2004/11/08 10:09
58	1	US-6344809-\$.did.	DERWENT	2004/11/08 10:10
59	2	(monolithic adj isolator) not kanekawa.in. and @pd>20040422	USPAT;	2004/11/08 10:10
•	_	(Marianana ad) nasasas) nasasasasasasas and espa 200 to 122	US-PGPUB	200 17 1700 10:10
60	403	trench adj isolation and soi and @pd>20040422	USPAT;	2004/11/08 10:13
	,,,,	2001012	US-PGPUB;	200 11 1100 10:10
			EPO; JPO;]
			DERWENT;]
			IBM_TDB	
61	2970	(soi silicon-on-insulator) and @pd>20040422	USPAT;	2004/11/08 10:13
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
62			IBM_TDB	
	2439	trench near3 isolation and @pd>20040422	USPAT;	2004/11/08 10:13
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
	0	(mosfet misfet near3 series) and (trench adj isolation and soi) not (soi silicon-on-insulator)	USPAT;	2004/11/08 10:14
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
64	3	mosfet and (ignition adj coil and fuel adj injection) and @pd>20040422	IBM_TDB	2004/44/00 40:44
	3	moster and fightion adjicon and rider adjinjection) and @pd/20040422	USPAT; US-PGPUB;	2004/11/08 10:14
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
65	4	mosfet WITH (ignition adj coil or fuel adj injection) and @pd>20040422	USPAT;	2004/11/08 10:14
	'	ביים ביים ביים ביים ביים ביים ביים ביים	US-PGPUB;	200 11 1100 10.14
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
66	1	(*6060814*).PN.	USPAT;	2004/11/08 10:14
			US-PGPUB	
67	469	((257/347,350,396-399,496,507,510,513,516,521,586,594,618,622,626) or	USPAT;	2004/11/08 10:15
		(307/113,127,141.8) or (326/21,82) or (327/24,28,31)).CCLS. and @pd>20040422	US-PGPUB	
68	2	((US-5828141-\$ or US-4993396-\$).did.) and coil	USPAT	2004/11/08 10:15
69	1	((WO-9844687-\$ or US-6603807-\$).did.) and insulator	USPAT; JPO	2004/11/08 10:15